

EYP-BAL-1064-16000-4020-CDL02-0000

BROAD AREA LASER

GaAs Semiconductor Laser Diode Single Emitter Structure



Revision 1.00





05.06.2014



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General Product Information

Medical
Material Processing



Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-20		70
Operational Temperature at Case	T_{C}	°C	5		40
Forward Current	I_{F}	Α			24
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	W			18

non condensing
non condensing
Stress in excess of one of the Absolute Maximum
Ratings can cause permanent damage to the device.

Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		30
Forward Current	I _F	Α			22
Output Power	P_{opt}	W			16

Measurement Conditions / Comments
non condensing

Characteristics at T_{LD} = 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	1049	1064	1079
Spectral Width (FWHM)	$\Delta\lambda$	nm		5	8
Temperature Coefficient of Wavelength	$d\lambda$ / dT	nm / K		0.4	
Output Power @ I _F = 22 A	P _{opt}	W	16		
Slope Efficiency	η_{d}	W/A	0.6	0.9	
Threshold Current	I _{th}	А		1.0	2.5
Operational Current @ P _{opt} = 16 W	l _{op}	А		18	22
Voltage at Threshold	U_{th}	V	1.2		
Operational Voltage	U	V	1.4	1.6	2.2

Measurement Conditions / Comments				
$P_{opt} = 16 \text{ W}$				
total output measured with integrating sphere				
total output measured with integrating spriere				
$I_{F} = I_{th}$				
P _{opt} = 16 W				



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Characteristics at T_{amb} 25 °C at Begin Of Life

Single Emitter Structure



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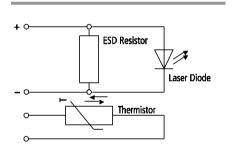
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Parameter	Symbol	Unit	min	typ	max
Differential Serial Resistance	R_{S}	mΩ	15	20	50
Stripe Width	W_s	μm		200	
Cavity Length	L	μm		4000	
Divergence parallel	$\Theta_{ }$	0	1.0	1.5	2.0
Divergence perpendicular	Θ_{\perp}	0	0.4	0.6	0.8
Beam Width parallel	S	mm	2	3	4
Beam Width perpendicular	F_{\perp}	mm	0.2	0.4	0.6
Spectral Mode (longitudinal)				Multi Mode	
Polarization				TE	

Measurement Conditions / Comments
Second Moment Full Angle
Second Moment Full Angle
Polarization parallel to base plate

ESD-Resistor

Parameter	Symbol	Unit	min	typ	max
Resistance	R_{ESD}	kΩ		1	



Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			4000	

$T_c = 25^{\circ} C$		



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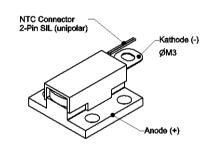
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Parameter	Symbol	Unit	min	typ	max
Emission Plane	h _{EP}	mm	7.75	7.85	7.95
CDL Package Footprint	wxl	mm x mm		25 x 25	

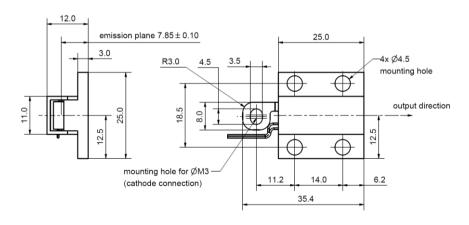
Measurement Conditions / Comments				

Package Pinout

Cathode (-)	Cable	
Anode (+)	Housing	
NTC	NTC Connector	



Package Drawings



Z11-SPEC-CDL02-BAL-0000



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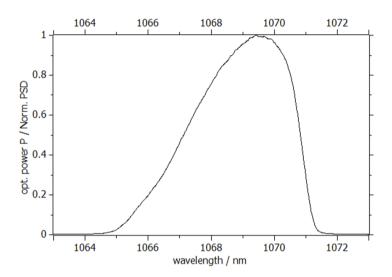






Typical Measurement Results

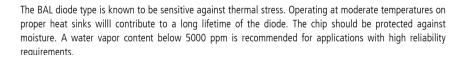
Emission Spectrum:



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

